

# G4M-1

## SINTERED GLASS JUNCTION AVALANCHE RECTIFIER

VOLTAGE : 1000V

CURRENT: 3.0A

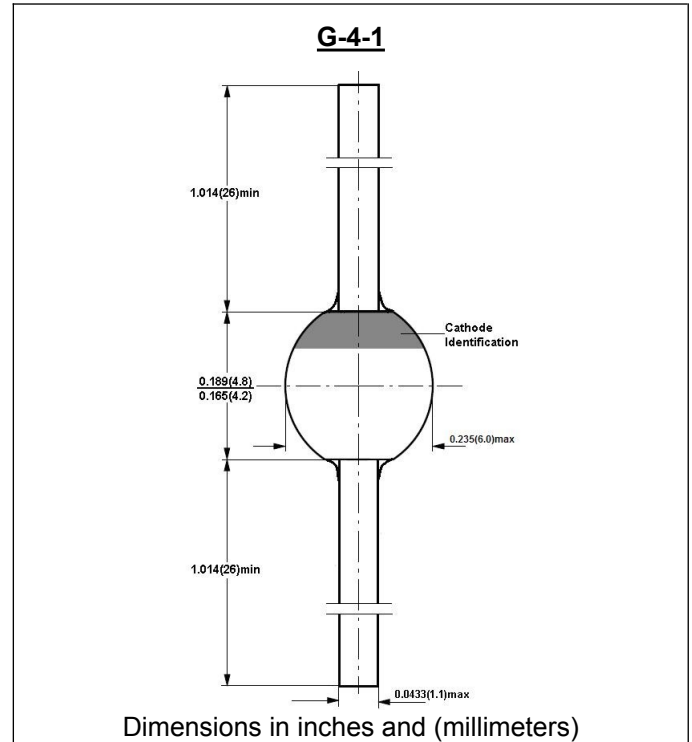


### FEATURE

Glass passivated  
Hermetically sealed package  
Low reverse current

### MECHANICAL DATA

Case: G-4 sintered glass case  
Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C  
Polarity: color band denotes cathode end  
Mounting position: any



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

	SYMBOL	G4M-1	units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	1000	V
Maximum RMS Voltage	$V_{RMS}$	700	V
Maximum DC blocking Voltage	$V_{DC}$	1000	V
Maximum Average Forward Rectified Current 3/8"lead length at $T_a=70^\circ C$	$I_{FAV}$	3.0	A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	$I_{FSM}$	100	A
Maximum Forward Voltage at rated Forward Current and 25°C	$V_F$	1.1	V
Maximum DC Reverse Current $T_a=25^\circ C$	$I_R$	1.0	$\mu A$
at rated DC Blocking Voltage $T_a=150^\circ C$		100	
Typical Reverse Recovery Time (Note 1)	$T_{rr}$	3.0	$\mu S$
Typical Junction Capacitance (Note 2)	$C_j$	40.0	pF
Typical Thermal Resistance (Note 3)	$R_{th}(ja)$	20.0	$^\circ C / W$
Storage and Operating Junction Temperature	$T_{stg}, T_j$	-65 to +175	$^\circ C$

Note:

1. Reverse Recovery Condition  $I_f = 0.5A, I_r = 1.0A, I_{rr} = 0.25A$
2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
3. Thermal Resistance from Junction to Ambient at 3/8"lead length, P.C. Board Mounted

## RATINGS AND CHARACTERISTIC CURVES G4M-1

